Protection for Lithium-Ion Batteries (3-serial cells) Monolithic IC MM1293

Outline

This IC provides protection for lithium ion batteries in the event of overcharging, overdischarging and overcurrents. When anomalies occur during charging or at other times and excessive voltages are applied, after a certain time has elapsed for each cell an external FET switch is turned off (overcharging detection); and in order to prevent overdischarge of the battery during discharge, when the voltage of individual batteries falls below a fixed voltage, an external FET switch is turned off (overdischarging detection), and the IC is put into low-consumption current mode. When large currents flow due to a short-circuit or other cause, an external MOS switch is turned off (overcurrent detection).

3-Cell Protection ICs

Temperature conditions A: $Ta=-25 \sim 75^{\circ}C$, B: $Ta=-20 \sim 70^{\circ}C$, C: $Ta=0 \sim 50^{\circ}C$, D: $Ta=0 \sim 40^{\circ}C$, E: $Ta=-20 \sim 25^{\circ}C$

Model	Package SSOP-16	Overcharge detection voltage (V)	Overcharge detection voltage temperature conditions	Overcharge detection hysteresis voltage (V)	Overdischarge detection voltage (V)	Overdischarge reset voltage (V)	Overcurrent detection voltage (mV)
MM1293	AJ	4.350±0.050	В	200±60	2.35±0.10	3.05±0.15	150±15
	BJ	4.250±0.050	В	200±60	2.40±0.10	3.10±0.15	150±15
	GJ	4.350±0.050	В	200±60	2.35±0.10	3.05±0.15	150±15

Features

Current consumption (overcharging)	VCELL > VCELLU	125μA typ.
2. Current consumption (normal operation)	$V_{\text{CELL}} < V_{\text{ALM}}$	30μA typ.
3. Current consumption (overdischarge)	VCELL < VCELLS	0.1µA max.
4. Overcharge sensing dead time	C=0.1µF	1.0S typ.
5. Overcharge sensing operation voltage	$V_{CELL}: L \rightarrow H$	A, G; 4.20V±150mV/CELL
		B; 4.10V±150mV/CELL
6. Overdischarge sensing dead time	C=0.1µF	1.0S typ.
7. Overcurrent detection voltage		0.15V typ.
8. Overcurrent protection circuit		A, B; Load open $250k\Omega$ or higher
		G; charging reset

9. Overcharge and overdischarve voltages as well as the overcurrent detection voltage can be changed upon request.

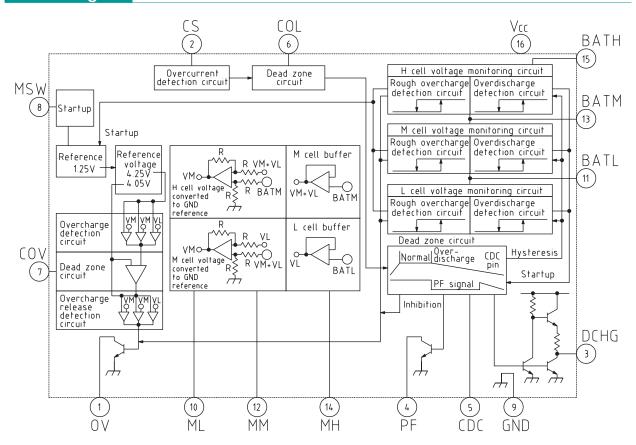
Package

SSOP-16

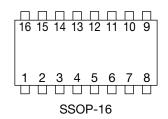
Applications

Lithium ion battery pack for notebook computers

Block Diagram



Pin Assignment



1	1 OV		GND	
2	CS	10	ML	
3	DCHG	11	BATL	
4	PF 12		MM	
5	CDC 13		BATM	
6	COL	14	MH	
7	COV	15	BATH	
8	MSW	16	Vcc	

Pin Assignment

Pin no.	Pin name	Input/output	Function
1	OV	Output	Overcharge detection output pin NPN transistor open collector output; normally high impedance, goes to L level on overdischarge
2	CS	Input	Overcurrent detection pin Monitors equivalent load current through source-drain voltage drop of discharge-controlling FET, and at or above the overcurrent detection voltage sets the DCHG pin to "H" and turns off the discharge-controlling FET. Following overcurrent detection, current is passed from this pin, and if the load is decreased, the overcurrent mode is canceled. Through this action there is a temporary consumption current (at the Vcc pin) of approx. 1 mA on resumption of discharge and detection of overdischarge. This function is disabled in overdischarge mode.
3	DCHG	Output	Pin driving the discharge-controlling FET (P-ch) Normally "L"; on overdischarge set to "H" Output pin for overdischarge detection signals
4	PF	Output	Overdischarge detection pin When the overdischarge detector detects overdischarge at the open collector output of the NPN transistor, this pin is turned on. A delay is provided by setting a dead time until discharge ends, so that by utilizing a reset or other signal from a CPU or some other controlling device, the equipment can be put into standby mode.
5	CDC	Input	Pin to set the dead time for overdischarge detection By connecting a capacitor between the CDC pin and GND, a dead time can be set. Pin to set the dead time for overcurrent detection
6	COL	Input	Pin to set the dead time for overcurrent detection By connecting a capacitor between the COL pin and GND, a dead time can be set. If NC, protection is triggered in a short amount of time; the dead time should be set according to the application.
7	COV	Input	Pin to set the dead time for overcharge detection By connecting a capacitor between the COV pin and GND, a dead time can be set.
8	MSW	Input	Pin to switch the cell voltage monitor on/off GND: monitor on, Vcc: monitor off The cell voltage monitor converts the different cell voltages to a GND-reference voltage and outputs it from the ML, MM and MH pins.
9	GND	Input	Ground pin
10	ML	Output	Monitor output pin for the L cell voltage
11	BATL	Input	Pin for input of L cell high-side voltage and M cell low-side voltage
12	MM	Output	Monitor output pin for the M cell voltage
13	BATM	Input	Pin for input of M cell high-side voltage and H cell low-side voltage
14	МН	Output	Monitor output pin for the H cell voltage
15	BATH	Input	Pin for input of H cell high-side voltage
16	Vcc	Input	Power supply input pin The same potential as the BATH pin should be input

Absolute Maximum Ratings

Item	Symbol	Ratings	Units
Storage temperature	Tstg	-40~+125	°C
Operating temperature	Topr	-20~+70	°C
Charge voltage	VBAT max.	18	V
Power supply voltage	Vcc max.	18	V
Voltage applied to OV pin	Vov max.	18	V
Allowable loss	Pd	300	mW

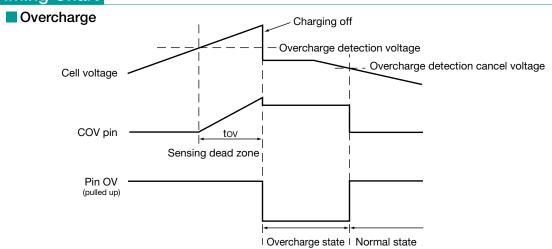
Recommended Operating Conditions

Item	Symbol	Ratings	Units
Operating temperature	Topr	-20~+70	°C
Operating voltage	Vopr	+2~+18	V

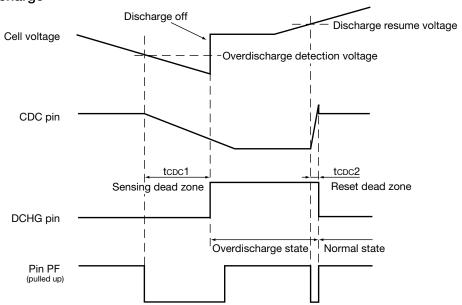
Electrical Characteristics (Except where noted otherwise, Ta=25°C, Vcc=15V, Vcell=Vbath=Vbath=Vbath) Models listed MM1293B

Item	Symbol	Measurement conditions	Min.	Тур.	Max.	Units
Consumption current (Vcc pin) 1	Icc1	Vcell=4.4V		125	250	μA
Consumption current (Vcc pin) 2	Icc2	Vcell=3.5V		30	60	μA
Consumption current (Vcc pin) 3	Icc3	Vcell=2.2V			0.1	μA
Consumption current (BATH pin) 1	Іватн1	Vcell=4.4V		11	22	μA
Consumption current (BATH pin) 2	Іватн2	Vcell=3.5V		5	10	μA
Consumption current (BATH pin) 3	Іватн3	Vcell=2.2V		2	4	μA
BATM pin input current 1	ІватМ	Vcell=3.5V			±300	nA
BATM pin input current 2	ІватМА	Vcell=4.4V	-0.6	-0.3	0	μA
BATL pin input current 1	IBATL	Vcell=3.5V			±300	nA
BATL pin input current 2	IBATLA	Vcell=4.4V	-0.6	-0.3	0	μA
Overcharge detection voltage	VCELLU	Ta=-20~+70°C, Vcell: 3.7V→4.5V	4.20	4.25	4.30	V
Overcharge detection	VcellO	Vcell: 4.5V→3.7V	VCELLU	VCELLU	VCELLU	v
release voltage	V CELLO		-260mV	-200mV	-140mV	•
Overcharge sensing dead time	tov	Cov=0.1µF	0.5	1.0	1.5	s
Overcharge sensing operation voltage	VALM	Vcell: 3.5V→4.4V	3.95	4.10	4.25	V
Overdischarge sensing hysteresis voltage	∠VALM	Vcell: 4.4V→3.5V	120	200	300	mV
Overdischarge detection voltage	VCELLS	Vcell: 3.5V→2.0V	2.30	2.40	2.50	V
Discharge resume voltage	VCELLD	Vcell: 2.0V→3.5V	2.95	3.10	3.25	V
Overdischarge sensing hysteresis voltage	∠VcsD	VCELLD-VCELLS	490	700	910	mV
Overdischarge sensing dead time	tcdc1	Ccdc=0.1μF	0.5	1.0	1.5	s
Overdischarge reset dead time	tcdc2	Ccdc=0.1µF, Vcs=Vcc+0.3V		7		ms
Overcurrent detection voltage	Voc	Vcc-Vcs, Dchg	0.135	0.150	0.165	V
Overcurrent sensing dead time	tcol1	Ссол=0.001µF, Дсн	5	10	15	ms
Overcurrent reset dead time	tcol2	Ccol=0.001µF, Dchg	5	10	15	ms
Overcurrent sensing delay time	tcol3	Ccol=0, Dchg		150		μs
Overcurrent reset delay time	tcol4	Ccol=0, Dchg		150		μs
Overcurrent protection release			Open-	load co	ndition	250kΩ
DCHG pin source current	IsoDсн	VCELL < VCELLS, SW1 : A, VDCHG=VCC-1.8V	20			μA
DCHG pin sync current	IsiDcн	VCELL > VCELLS, SW1: A, VDCHG=0.8V	20			μA
DCHG pin output voltage H	VтнDcH	Vcc-Vdchg, Iso=20μA, SW1 : B			1.8	V
DCHG pin output voltage L	VтнDcL	VDCHG-GND, ISI=-20µA, SW1 : B			0.8	V
OV pin sync current	IsiOv	Vov=0.4V, Ta=-20~+70°C	0.2			mA
PF pin sync current	IsiPf	Vpf=0.4V, Ta=-20~+70°C	10			μA

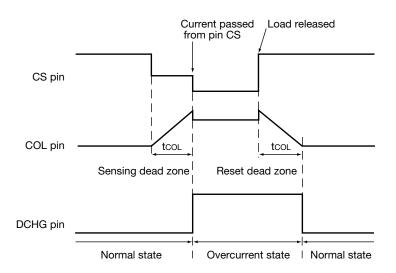
Timing Chart



Overdischarge

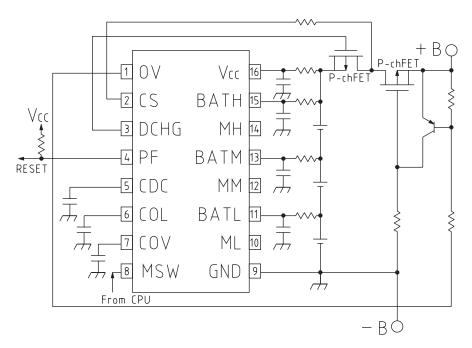


Overcurrent



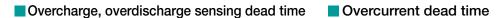
 0.01μ

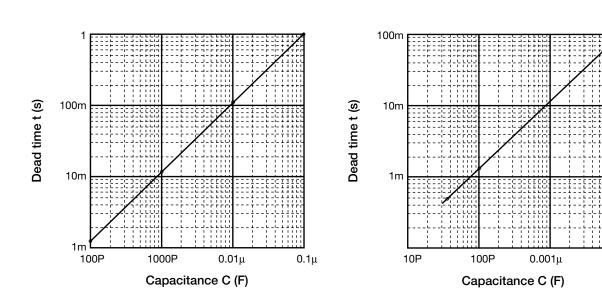
Application circuits



Note: Applicable circuits shown are typical examples provided for reference purposes. Mitsumi cannot assume responsibility for any problems arising out of the use of these circuits or for any infringement of third party patent and other right due to same.

Characteristics





Note: The above characteristics are representative and are not guaranteed.